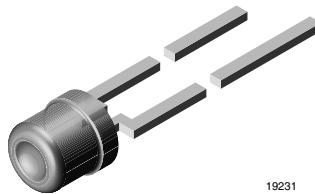


Backlighting LED in Ø 3 mm Tinted Non-Diffused Package



19231

DESCRIPTION

The TLV.4200 series was developed for backlighting. Due to its special shape the spatial distribution of the radiation is qualified for backlighting.

To optimize the brightness of backlighting a custom-built reflector (with scattering) is required. Uniform illumination can be enhanced by covering the front of the reflector with diffusor material.

This is a flexible solution for backlighting different areas.

PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: 3 mm backlighting
- Product series: standard
- Angle of half intensity: $\pm 85^\circ$

FEATURES

- High light output
- Wide viewing angle
- Categorized for luminous flux
- Tinted clear package
- Low power dissipation
- Low self heating
- Rugged design
- High reliability
- Lead (Pb)-free device
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



(e1)

APPLICATIONS

- Backlighting of display panels, LCD displays, symbols on switches, keyboards, graphic boards and measuring scales
- Illumination of large areas e.g. dot matrix displays

PARTS TABLE

PART	COLOR, LUMINOUS FLUX	TECHNOLOGY
TLVH4200	Red, $\phi_V > 10 \text{ mlm}$	GaAsP on GaP
TLVH4201	Red, $\phi_V = (40 \text{ to } 125) \text{ mlm}$	GaAsP on GaP
TLVS4200	Soft orange, $\phi_V > 10 \text{ mlm}$	GaAsP on GaP
TLVY4200	Yellow, $\phi_V > 10 \text{ mlm}$	GaAsP on GaP
TLVG4200	Green, $\phi_V > 10 \text{ mlm}$	GaP on GaP
TLVP4200	Pure green, $\phi_V > 4 \text{ mlm}$	GaP on GaP

ABSOLUTE MAXIMUM RATINGS¹⁾ TLVH4200, TLVS4200, TLVY4200, TLVG4200, TLVP4200

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage ²⁾		V_R	6	V
DC Forward current	$T_{amb} \leq 60^\circ C$	I_F	30	mA
Surge forward current	$t_p \leq 10 \mu s$	I_{FSM}	1	A
Power dissipation		P_V	90	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 55 to + 100	°C
Soldering temperature	$t \leq 5 s$, 2 mm from body	T_{sd}	260	°C
Thermal resistance junction/ambient		R_{thJA}	400	K/W

Note:

1) $T_{amb} = 25^\circ C$, unless otherwise specified

2) Driving the LED in reverse direction is suitable for a short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS¹⁾ TLVH4200, RED

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous flux	$I_F = 15 \text{ mA}$	TLVH4200	ϕ_V	10	25		mlm
		TLVH4201	ϕ_V	40		125	mlm
Dominant wavelength	$I_F = 10 \text{ mA}$		λ_d	612		625	nm
Peak wavelength	$I_F = 10 \text{ mA}$		λ_p		635		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		φ		± 85		deg
Forward voltage	$I_F = 20 \text{ mA}$		V_F		2.4	3	V
Reverse voltage	$I_R = 10 \mu A$		V_R	6	15		V
Junction capacitance	$V_R = 0$, $f = 1 \text{ MHz}$		C_j		50		pF

Note:

1) $T_{amb} = 25^\circ C$, unless otherwise specified**OPTICAL AND ELECTRICAL CHARACTERISTICS¹⁾ TLVS4200, SOFT ORANGE**

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous flux	$I_F = 15 \text{ mA}$	ϕ_V	10	25		mlm
Dominant wavelength	$I_F = 10 \text{ mA}$	λ_d	598		611	nm
Peak wavelength	$I_F = 10 \text{ mA}$	λ_p		605		nm
Angle of half intensity	$I_F = 10 \text{ mA}$	φ		± 85		deg
Forward voltage	$I_F = 20 \text{ mA}$	V_F		2.4	3	V
Reverse voltage	$I_R = 10 \mu A$	V_R	6	15		V
Junction capacitance	$V_R = 0$, $f = 1 \text{ MHz}$	C_j		50		pF

Note:

1) $T_{amb} = 25^\circ C$, unless otherwise specified

**OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ TLVY4200, YELLOW**

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous flux	$I_F = 15 \text{ mA}$	ϕ_V	10	20		mlm
Dominant wavelength	$I_F = 10 \text{ mA}$	λ_d	581		594	nm
Peak wavelength	$I_F = 10 \text{ mA}$	λ_p		585		nm
Angle of half intensity	$I_F = 10 \text{ mA}$	φ		± 85		deg
Forward voltage	$I_F = 20 \text{ mA}$	V_F		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$	V_R	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	C_j		50		pF

Note:

1) $T_{amb} = 25^\circ\text{C}$, unless otherwise specified**OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ TLVG4200, GREEN**

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous flux	$I_F = 15 \text{ mA}$	ϕ_V	10	30		mlm
Dominant wavelength	$I_F = 10 \text{ mA}$	λ_d	562		575	nm
Peak wavelength	$I_F = 10 \text{ mA}$	λ_p		565		nm
Angle of half intensity	$I_F = 10 \text{ mA}$	φ		± 85		deg
Forward voltage	$I_F = 20 \text{ mA}$	V_F		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$	V_R	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	C_j		50		pF

Note:

1) $T_{amb} = 25^\circ\text{C}$, unless otherwise specified**OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ TLVP4200, PURE GREEN**

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous flux	$I_F = 15 \text{ mA}$	ϕ_V	4	10		mlm
Dominant wavelength	$I_F = 10 \text{ mA}$	λ_d	555		565	nm
Peak wavelength	$I_F = 10 \text{ mA}$	λ_p		555		nm
Angle of half intensity	$I_F = 10 \text{ mA}$	φ		± 85		deg
Forward voltage	$I_F = 20 \text{ mA}$	V_F		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$	V_R	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	C_j		50		pF

Note:

1) $T_{amb} = 25^\circ\text{C}$, unless otherwise specified

LUMINOUS FLUX CLASSIFICATION

GROUP	LUMINOUS FLUX (MLM)	
STANDARD	MIN.	MAX.
P	4.0	8.0
Q	6.3	12.5
R	10	20
S	16	32
T	25	50
U	40	80
V	63	125
W	100	200
X	130	260
Y	180	360
Z	240	480

Note:

Luminous flux is tested at a current pulse duration of 25 ms and an accuracy of $\pm 11\%$.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each bag (there will be no mixing of two groups in each bag).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one bag.

In order to ensure availability, single wavelength groups will not be orderable.

COLOR CLASSIFICATION

GROUP	DOM. WAVELENGTH (NM)							
	SOFT ORANGE		YELLOW		GREEN		PURE GREEN	
	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.
0							555	559
1	598	601	581	584			558	561
2	600	603	583	586			560	563
3	602	605	585	588	562	565	562	565
4	604	607	587	590	564	567		
5	606	609	589	592	566	569		
6	608	611	591	594	568	571		
7					570	573		
8					572	575		

Note:

Wavelengths are tested at a current pulse duration of 25 ms.

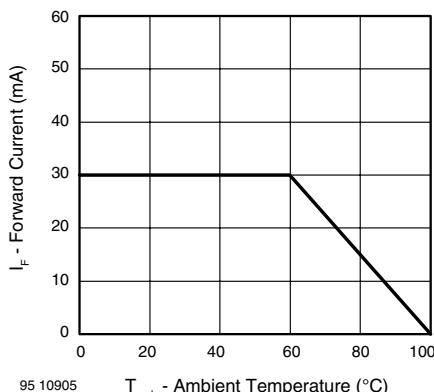
TYPICAL CHARACTERISTICS
 $T_{amb} = 25 \text{ }^{\circ}\text{C}$, unless otherwise specified


Figure 1. Forward Current vs. Ambient Temperature

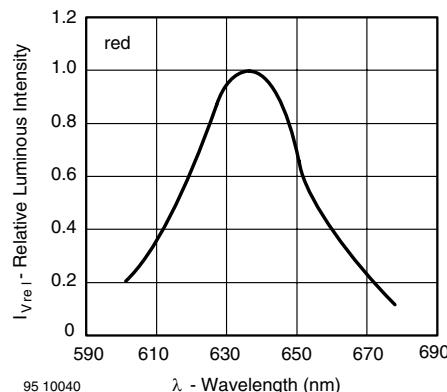


Figure 4. Relative Intensity vs. Wavelength

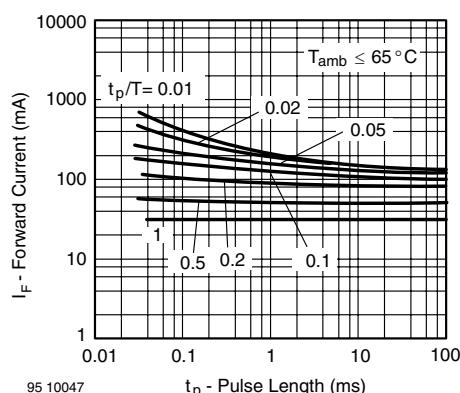


Figure 2. Forward Current vs. Pulse Length

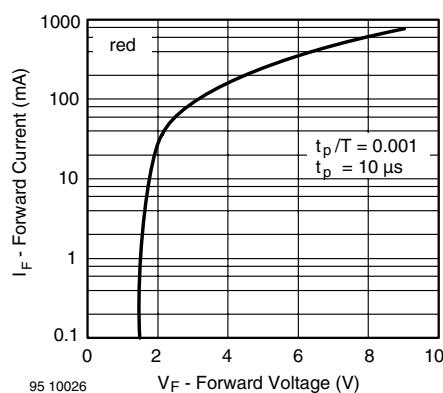


Figure 5. Forward Current vs. Forward Voltage

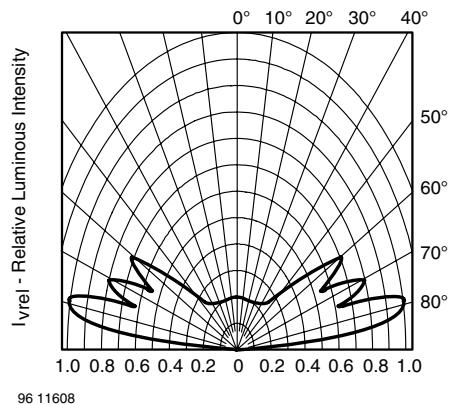


Figure 3. Rel. Luminous Intensity vs. Angular Displacement for 90 ° Emission Angle

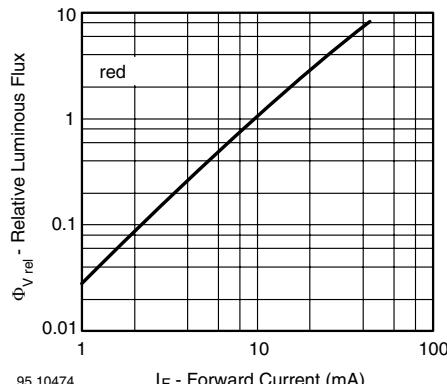


Figure 6. Relative Luminous Flux vs. Forward Current

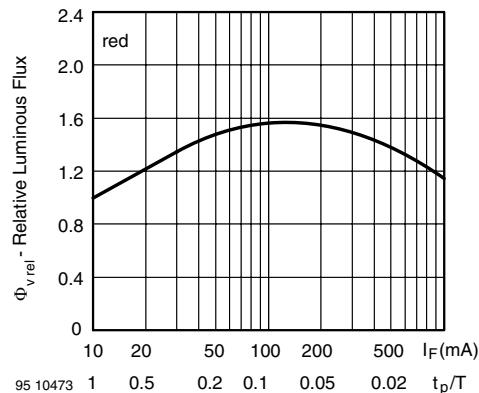


Figure 7. Rel. Luminous Flux vs. Forw. Current/Duty Cycle

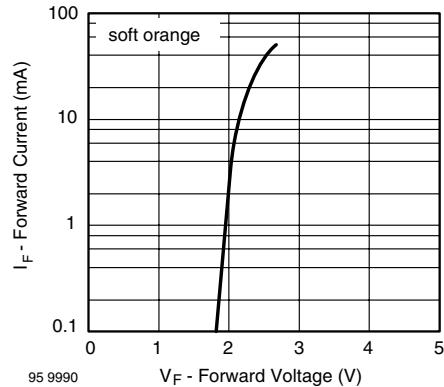


Figure 10. Forward Current vs. Forward Voltage

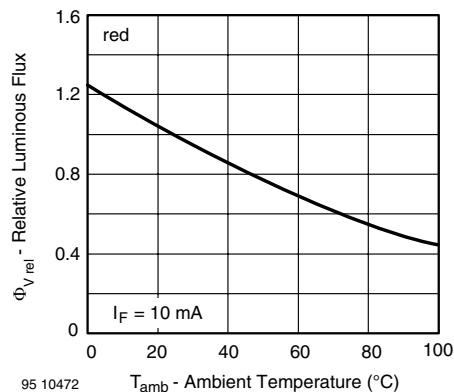


Figure 8. Rel. Luminous Flux vs. Ambient Temperature

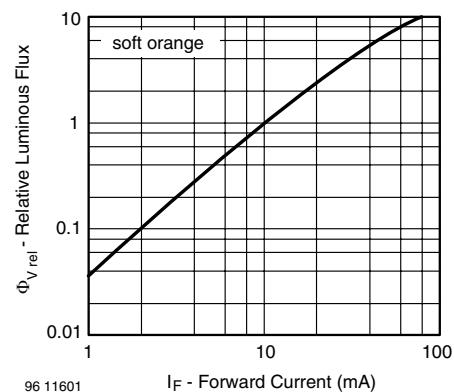


Figure 11. Relative Luminous Flux vs. Forward Current

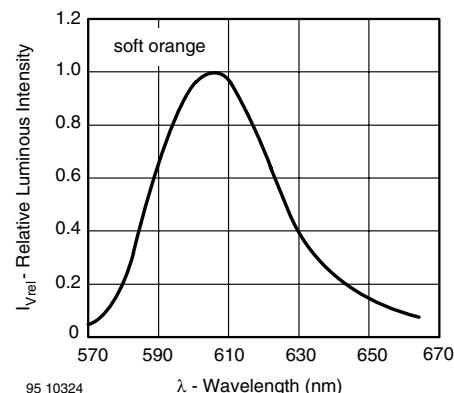


Figure 9. Relative Intensity vs. Wavelength

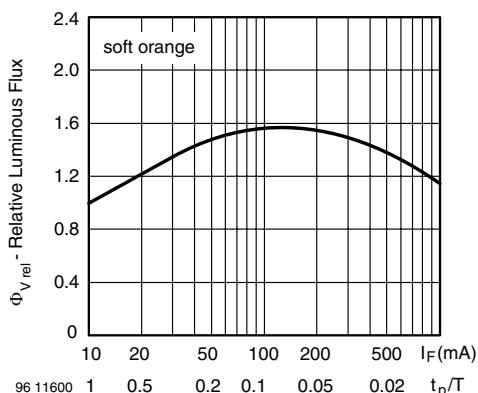
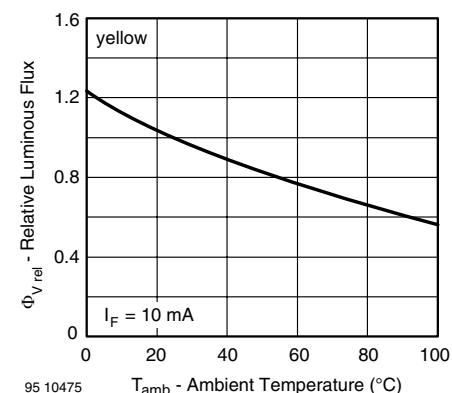
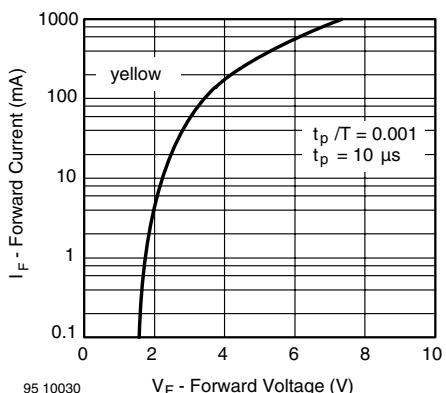
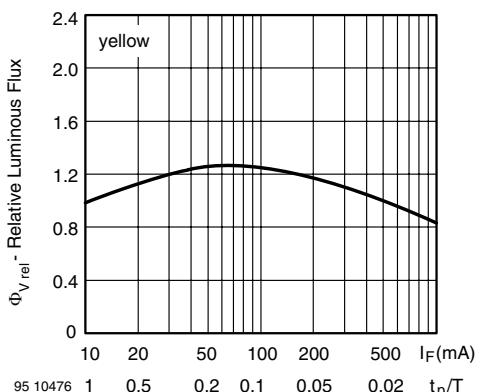
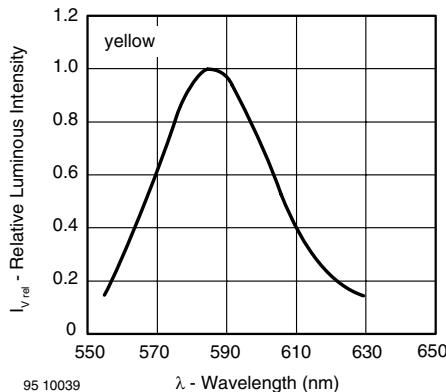
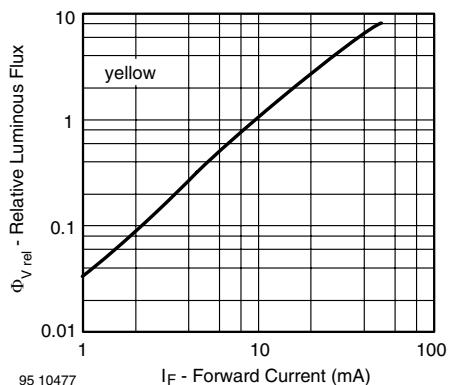
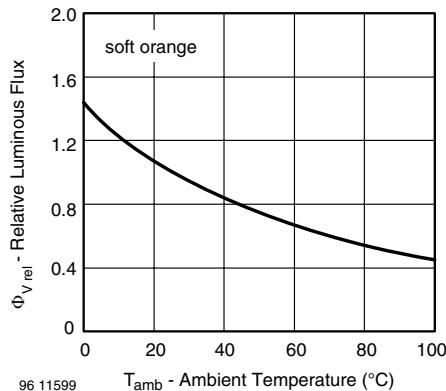


Figure 12. Rel. Luminous Flux vs. Forw. Current/Duty Cycle



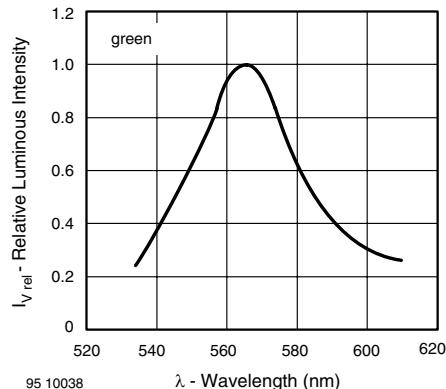


Figure 19. Relative Intensity vs. Wavelength

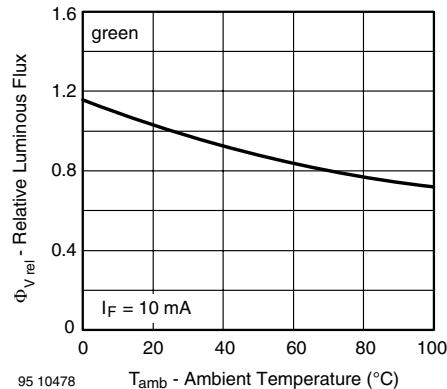


Figure 22. Rel. Luminous Flux vs. Ambient Temperature

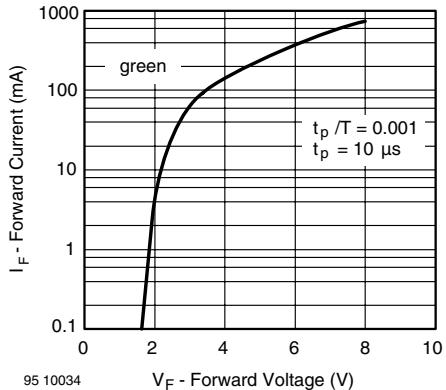


Figure 20. Forward Current vs. Forward Voltage

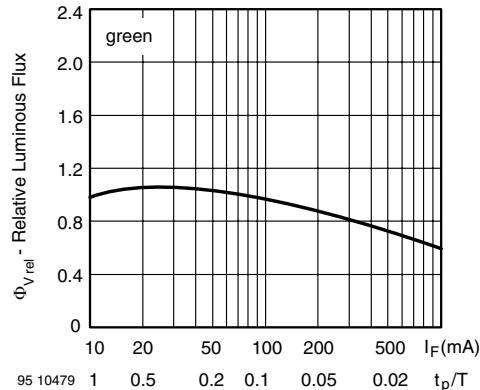


Figure 23. Rel. Luminous Flux vs. Forw. Current/Duty Cycle

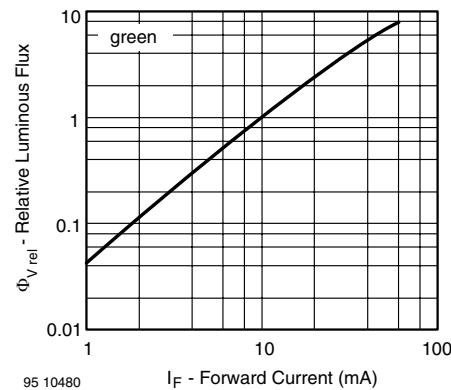


Figure 21. Relative Luminous Flux vs. Forward Current

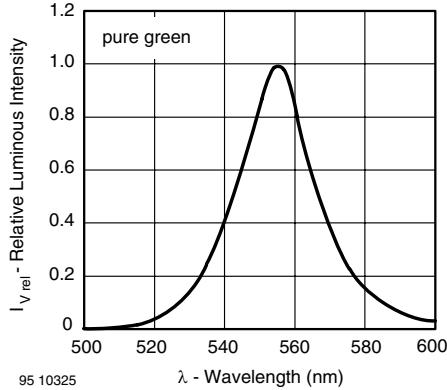


Figure 24. Relative Intensity vs. Wavelength

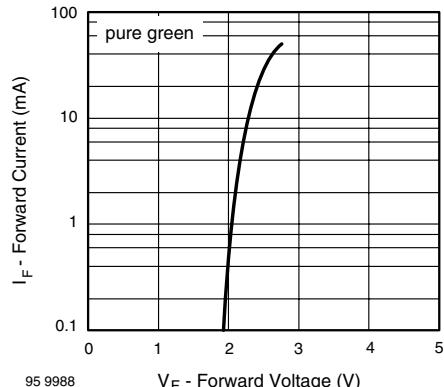


Figure 25. Forward Current vs. Forward Voltage

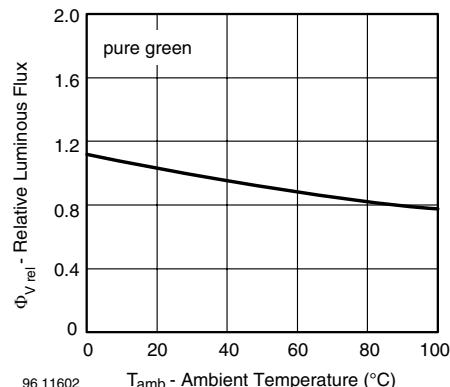


Figure 28. Rel. Luminous Flux vs. Ambient Temperature

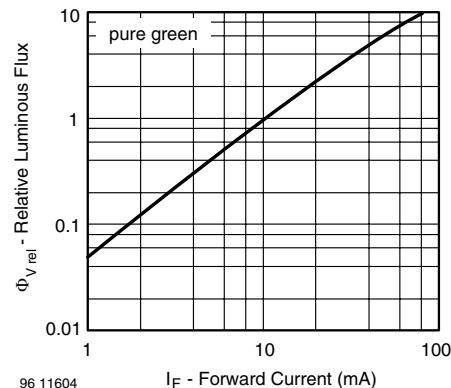


Figure 26. Relative Luminous Flux vs. Forward Current

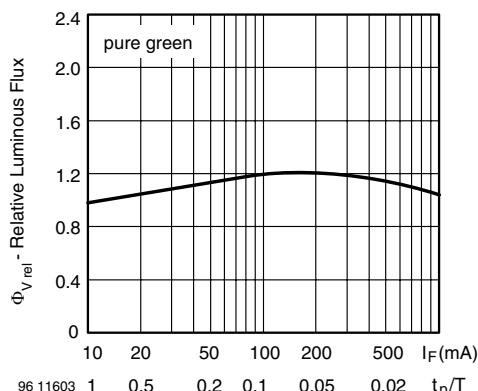
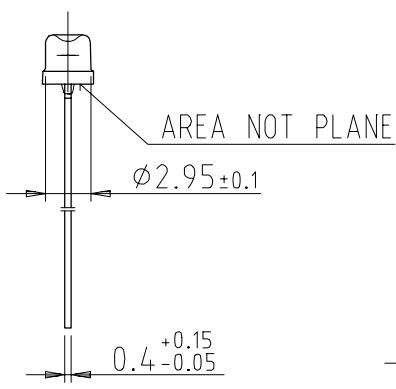
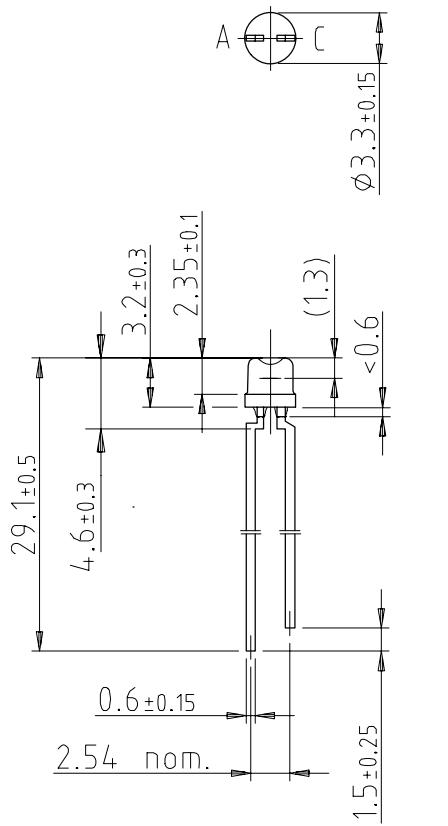
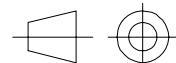


Figure 27. Rel. Luminous Flux vs. Forw. Current/Duty Cycle

PACKAGE DIMENSIONS in millimeters

9510954

technical drawings
according to DIN
specifications

**OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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